



Product Summary

BV _{DSS}	RDS(ON) max	Ι _D T _A = +25°C
-30V	95mΩ @ V _{GS} = -10V	-2.5A
-30 V	145mΩ @ V _{GS} = -4.5V	-2.0A

Description and Applications

This new generation MOSFET is designed to minimize the on-state resistance ($R_{DS(ON)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Boost Switch
- Power Management Functions
- Analog Switch
- Load Switch

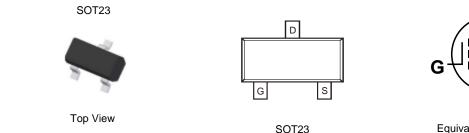
30V P-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 3
- Terminals Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)



Equivalent Circuit

Ordering Information (Note 4)

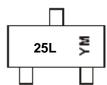
	Part Number	Case	Packaging		
	DMP3125L-7	SOT23	3,000/Tape & Reel		
DMP3125L-13		SOT23	10,000/Tape & Reel		
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.					

No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
 See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



25L = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: E = 2017) M = Month (ex: 9 = September)

Date Code Key

Year	2017	2018	20	019	2020	2021	1	2022	2023	202	24	2025
Code	E	F		G	Н			J	K	L	-	М
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

and Lead-free.



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	-30	V		
Gate-Source Voltage	V _{GSS}	±20	V		
Continuous Drain Current (Note 6) Vcs = -10V		T _A = +25°C T _A = +70°C	ID	-2.5 -2.0	А
Maximum Continuous Body Diode Forward Current (ls	-1.5	A		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	-10	A		

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

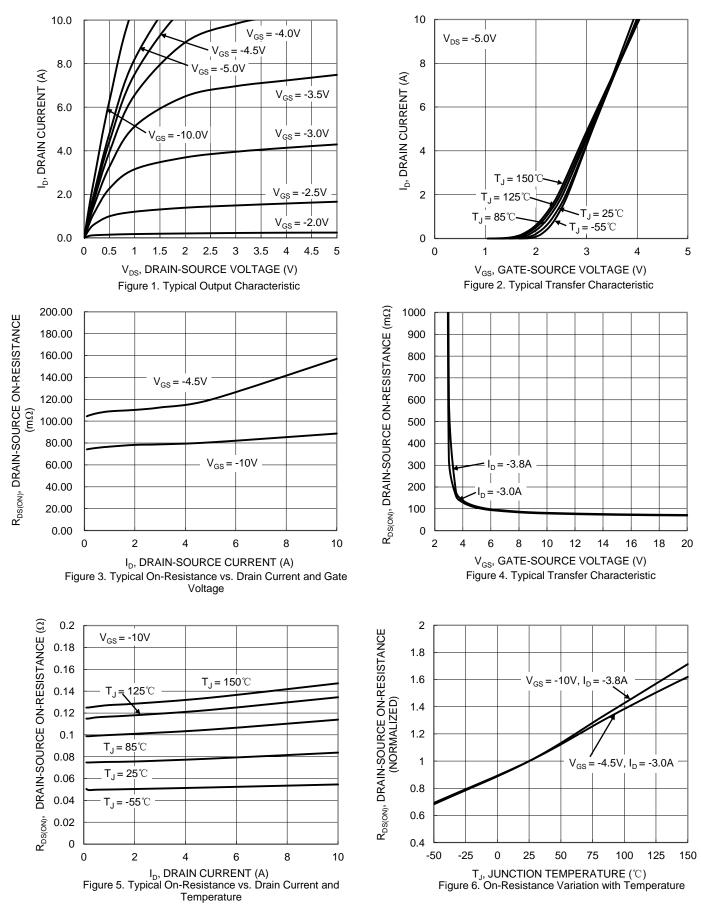
Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	0.65	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{ heta}JA$	191	°C/W
Total Power Dissipation (Note 6)	·	PD	1.2	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{ heta}$ JA	103	°C/W
Operating and Storage Temperature Range		T _{J,} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						1
Drain-Source Breakdown Voltage	BV _{DSS}	-30	—	_	V	$V_{GS} = 0V, I_D = -250\mu A$
Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$	I _{DSS}	_	—	-1	μA	$V_{DS} = -30V, V_{GS} = 0V$
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V _{GS(TH)}	-1.0		-2.1	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$
Static Drain-Source On-Resistance	C	—	76	95	mΩ	$V_{GS} = -10V, I_D = -3.8A$
Static Drain-Source On-Resistance	R _{DS(ON)}	_	108	145	11122	$V_{GS} = -4.5V, I_D = -3.0A$
Diode Forward Voltage	V _{SD}	_	-0.85	-1.2	V	$V_{GS} = 0V, I_{S} = -2.7A$
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	—	254	—	pF	
Output Capacitance	Coss	—	14	—	pF	V _{DS} = -25V, V _{GS} = 0V f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}	—	7	—	pF	
Gate Resistance	Rg	—	54	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$
Total Gate Charge	Qg	—	3.1	—	nC	
Gate-Source Charge	Q _{gs}	_	0.8	—	nC	V _{GS} = -4.5V, V _{DS} = -15V I _D = -3.8A
Gate-Drain Charge	Q_gd	_	1.4	—	nC	103.0A
Turn-On Delay Time	t _{D(ON)}	_	3.5	—	ns	
Turn-On Rise Time	t _R	_	6.3	—	ns	V _{DS} = -15V, V _{GS} = -10V,
Turn-Off Delay Time	tD(OFF)	_	21.8	—	ns	R _G = 6.0Ω, I _D = -1A
Turn-Off Fall Time	tF	—	13.1	—	ns	
Reverse Recovery Time	t _{RR}	_	9.6	_	ns	I _F = -1.0A, di/dt = 100A/µs
Reverse Recovery Charge	Q _{RR}	_	2.4	_	nC	I _F = -1.0A, di/dt = 100A/µs

 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing. Notes:



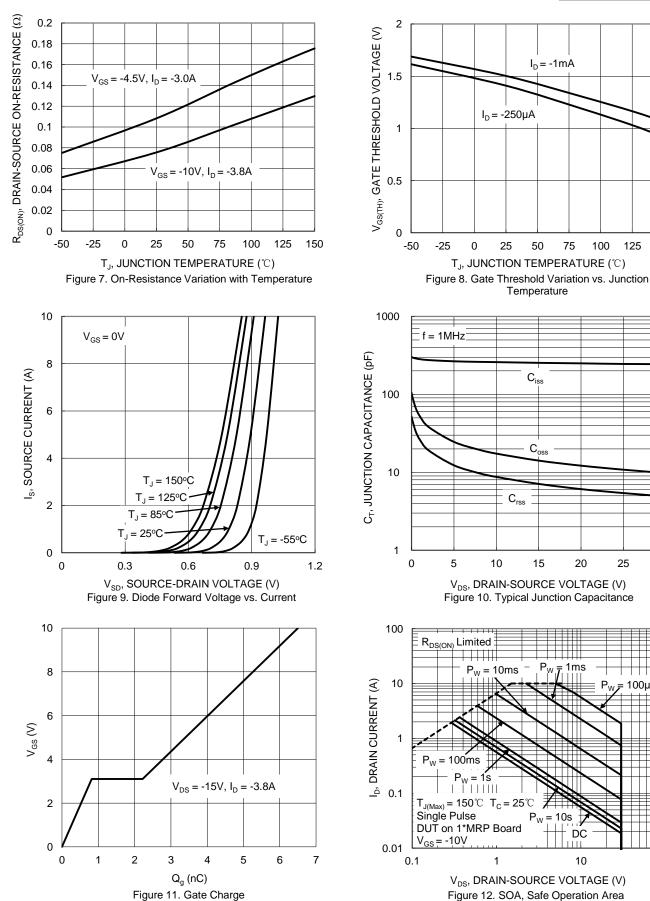






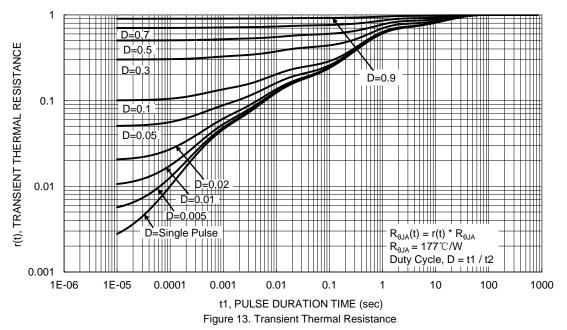
150

30



100



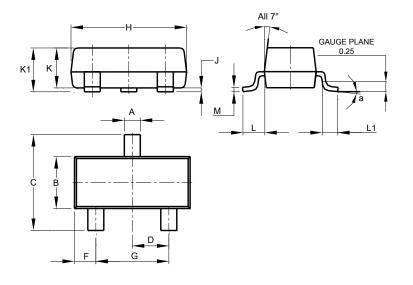




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

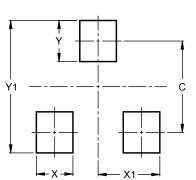
SOT23



	SOT23								
Dim	Min	Max	Тур						
Α	0.37	0.51	0.40						
В	1.20	1.40	1.30						
С	2.30	2.50	2.40						
D	0.89	1.03	0.915						
F	0.45	0.60	0.535						
G	1.78	2.05	1.83						
Н	2.80	3.00	2.90						
J	0.013	0.10	0.05						
ĸ	0.890	1.00	0.975						
K1	0.903	1.10	1.025						
L	0.45	0.61	0.55						
L1	0.25	0.55	0.40						
М	0.085	0.150	0.110						
а	0°	8°							
All	All Dimensions in mm								

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9



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